

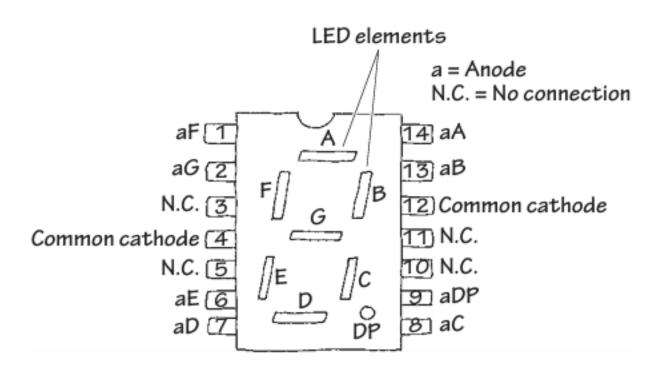
# ECE 105: Introduction to Electrical Engineering

Lecture 8
Optoelectronics
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Rehan Kapadia

### The seven-segment display



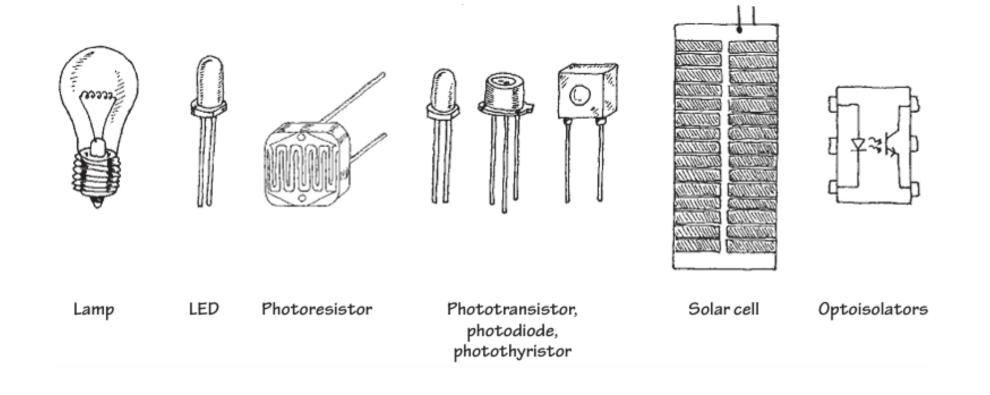
### **LED Displays**





# Light-based devices

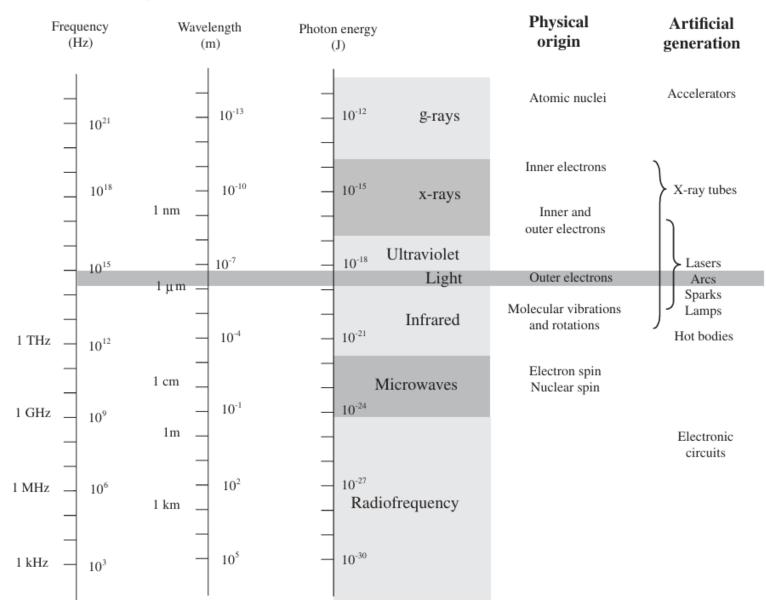




### Artificially generating light

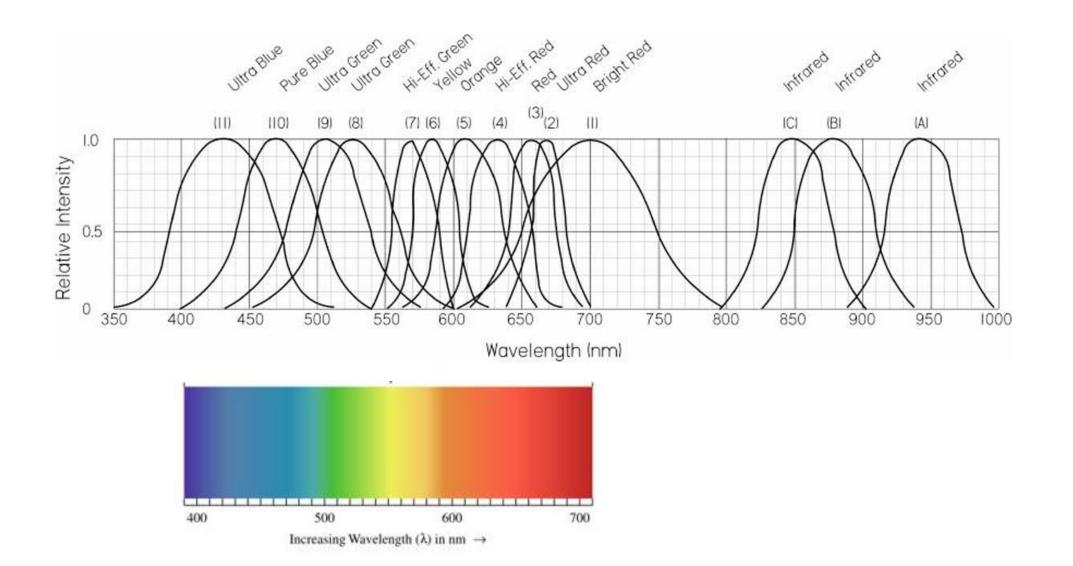


### Electromagnetic Spectrum



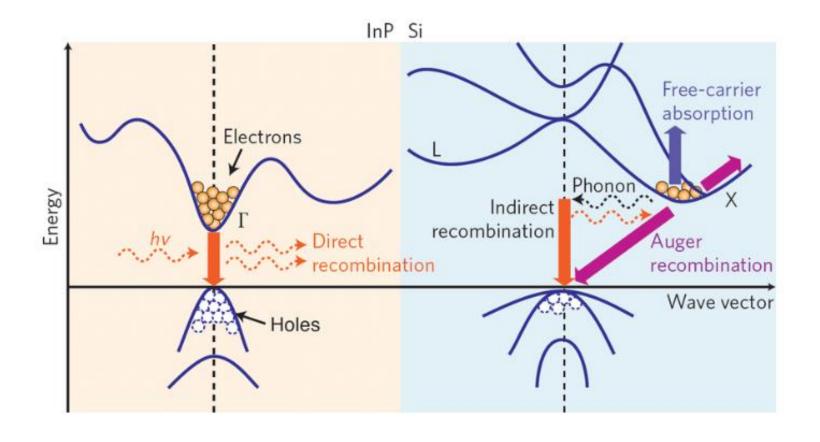
### LED emission spectra





### Direct vs indirect semiconductors





2 Energy band diagrams and major carrier transition processes in indium phosphide (direct bandgap) and silicon (indirect bandgap) crystals. Silicon, Germanium and some III/V compounds like GaP and AlAs are indirect bandgap semiconductors. InP, GaAs, GaN and other ternary (AlGaAs, InGaAs) and quaternary (InGaAsP, InAlAsP) compounds are direct bandgap semiconductors commonly used for photonic devices fabrication.

### LEDs are made out of non-silicon semiconductors

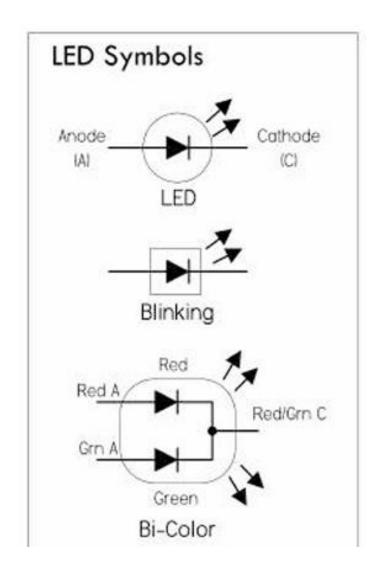


Color	Wavelength [nm]	Semiconductor material		
Infrared	λ > 760	Gallium arsenide (GaAs) Aluminium gallium arsenide (AlGaAs)		
Red	610 < A < 760	Aluminium gallium arsenide (AlGaAs) Gallium arsenide phosphide (GaAsP) Aluminium gallium indium phosphide (AlGaInP) Gallium(III) phosphide (GaP)		
Orange	590 < λ < 610	Gallium arsenide phosphide (GaAsP) Aluminium gallium indium phosphide (AlGaInP) Gallium(III) phosphide (GaP)		
Yellow	570 < λ < 590	Gallium arsenide phosphide (GaAsP) Aluminium gallium indium phosphide (AlGalnP) Gallium(III) phosphide (GaP)		
Green	500 < λ < 570	Traditional green: Gallium(III) phosphide (GaP) Aluminium gallium indium phosphide (AlGalnP) Aluminium gallium phosphide (AlGaP) Pure green: Indium gallium nitride (InGaN) / Gallium(III) nitride (GaN)		
Blue	450 < \lambda < 500	Zinc selenide (ZnSe) Indium gallium nitride (InGaN) Silicon carbide (SiC) as substrate Silicon (Si) as substrate—under development		
Violet	400 < λ < 450	Indium gallium nitride (InGaN)		
Purple	multiple types	Dual blue/red LEDs, blue with red phosphor, or white with purple plastic		
Ultraviolet	λ < 400	Diamond (235 nm) Boron nitride (215 nm) Aluminium nitride (AIN) (210 nm) Aluminium gallium nitride (AIGaN) Aluminium gallium indium nitride (AIGalnN)—down to 210		
Pink	multiple types	Blue with one or two phosphor layers: yellow with red, orange or pink phosphor added afterwards, or white with pink pigment or dye.		
White	Broad spectrum	Blue/UV diode with yellow phosphor		

Color	Name Color	Wavelength nm=1x10 <sup>-9</sup>	Voltage Drop (Forward Voltage)
0	White	395 - 530 nm	3-5 V
•	Ultraviolet	< 400 nm	3.1 - 4.4 V
•	Violet	400 - 450 nm	2.8 - 4.0 V
0	Blue	450 - 500 nm	2.5 - 3.7 V
•	Green	500 - 570 nm	1.9 - 4.0 V
0	Yellow	570 - 590 nm	2.1 - 2.2 V
0	Orange	590 - 610 nm	2.0 - 2.1 V
0	Red	610 - 760 nm	1.6 - 2.0 V
0	Infrared	> 760 nm	<1.9 V

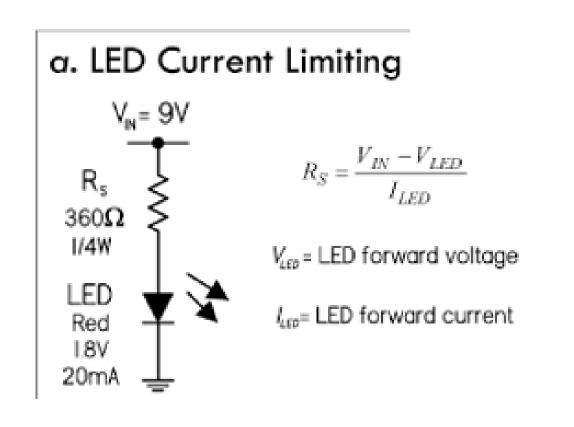
### LED symbols





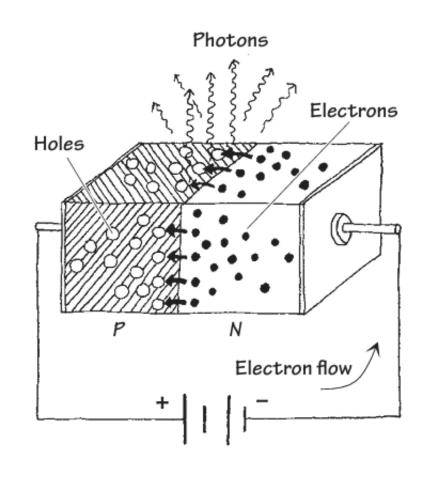
### LED driver circuit

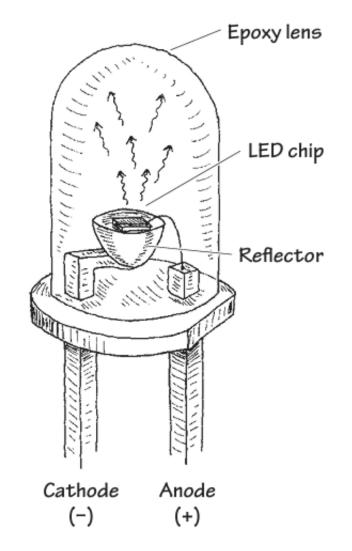




### LED is a diode

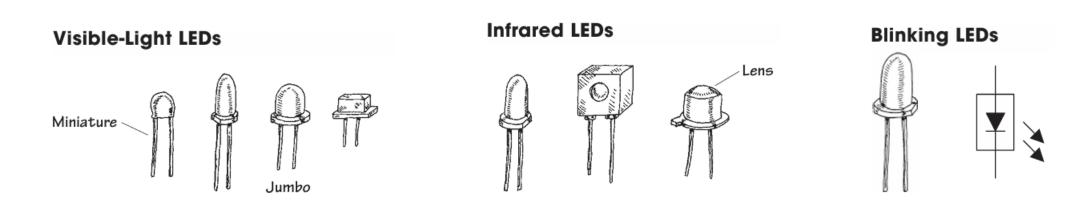


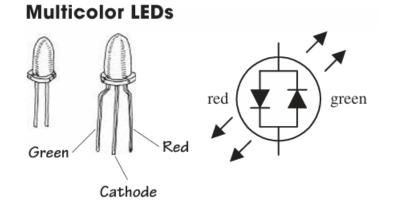




### LED packages

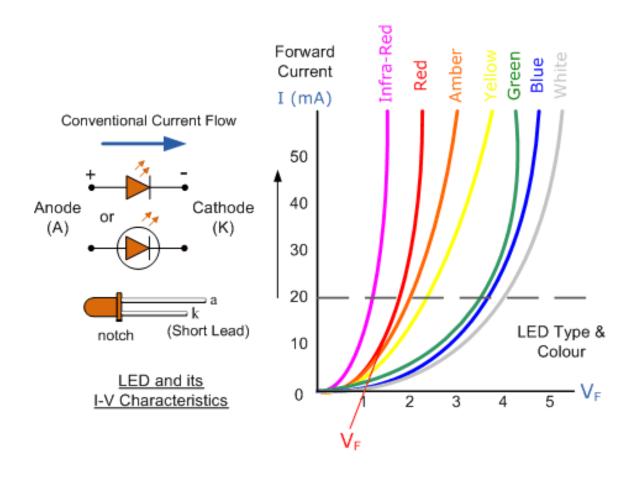






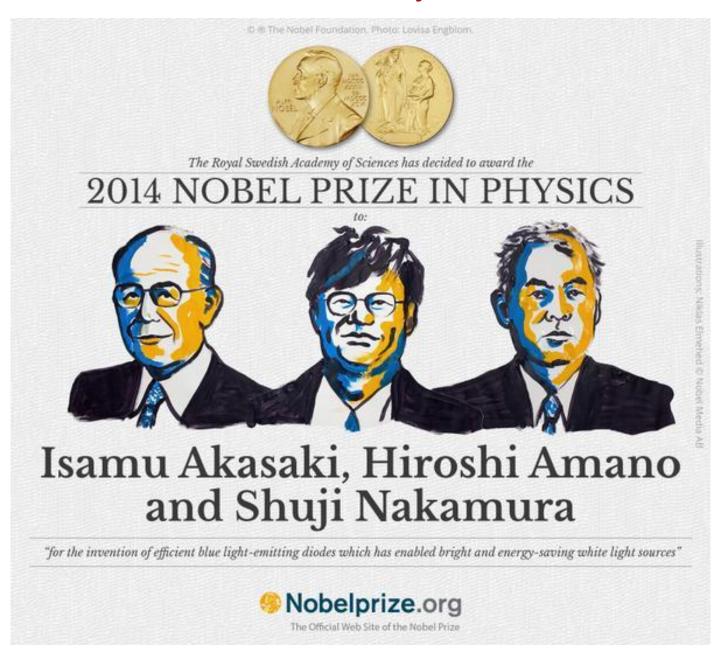
### IV characteristics for LEDs





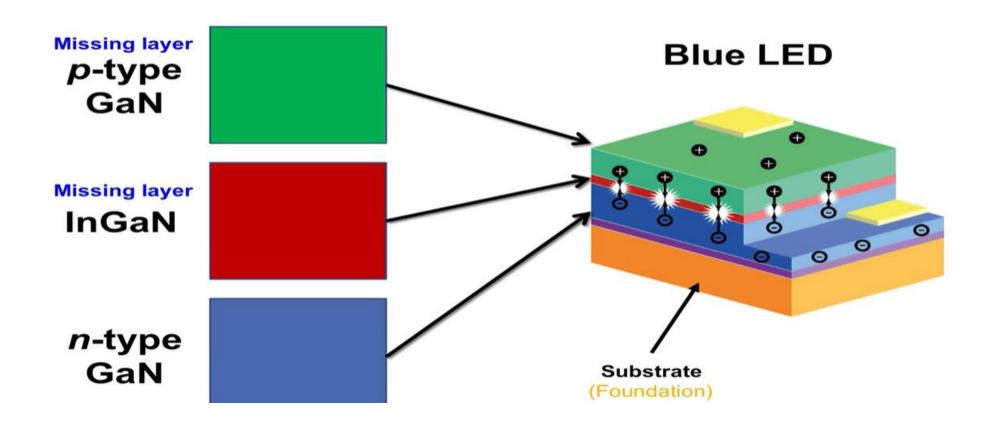
### Blue LED won the 2014 Nobel in Physics





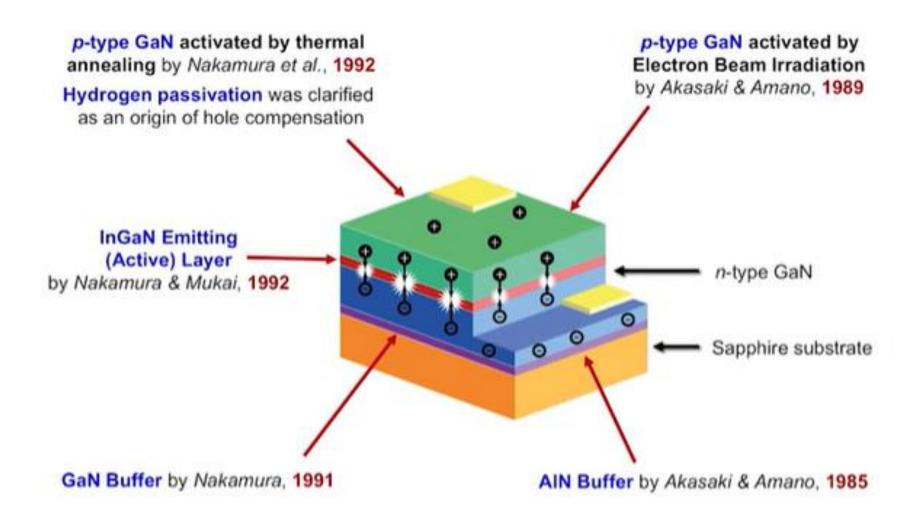
### Steps to get the Blue LED





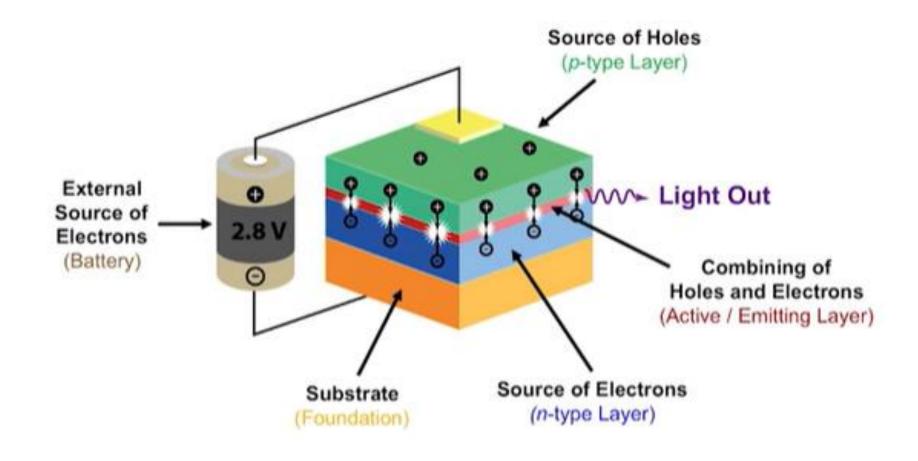
### InGaN LEDs





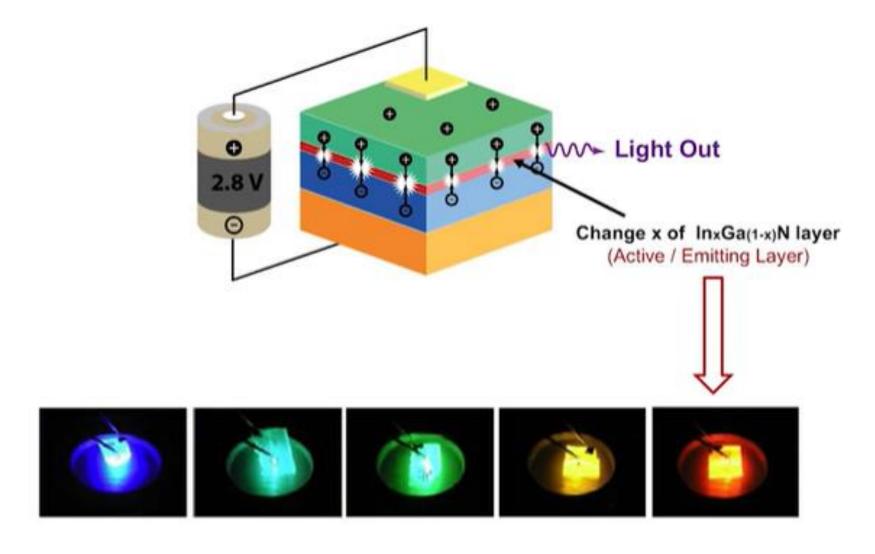
### LED colors – single color from on LED





### Changing emission colors – can you change color?



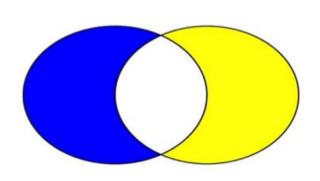


### How to get white light

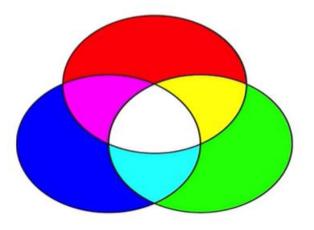


One LED can only produce one color (red, orange, yellow, green, blue, or violet)

To achieve white light, need to combine colors:



Blue + Yellow (Easiest)



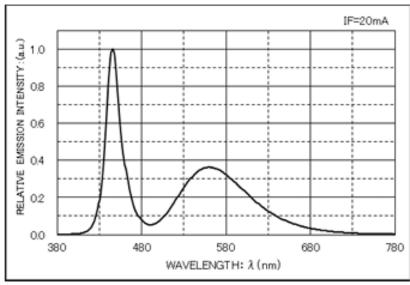
Blue + Green + Red (Highest Quality)

### The LED in our demo board

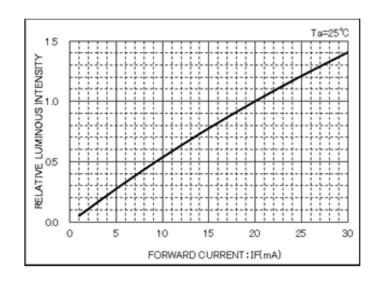


#### RELATIVE LUMINOUS INTENSITY - FORWARD CURRENT

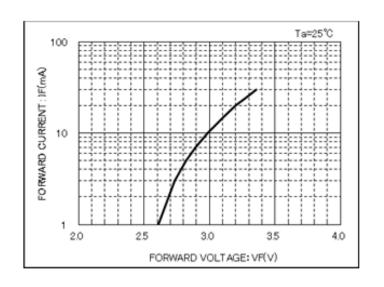
#### SPECTRUM



https://fscdn.rohm.com/en/products/databook/datasheet/opt o/led/chip\_mono/csl0416wbcw1-e.pdf

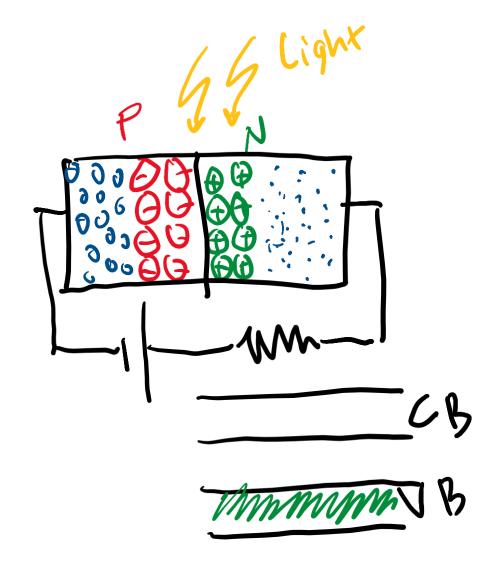


#### FORWARD CURRENT - FORWARD VOLTAGE



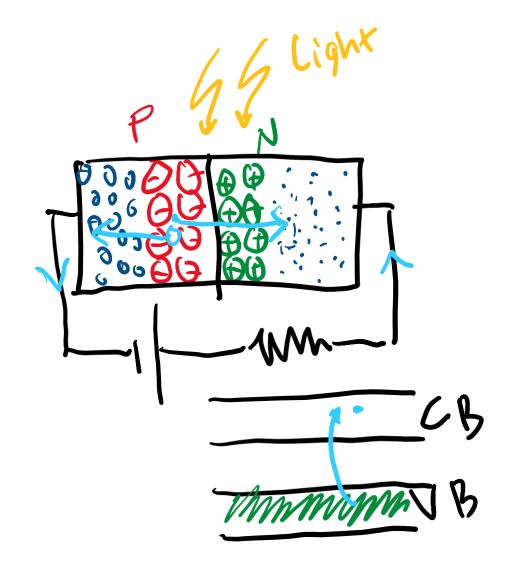
### How does a photodiode work





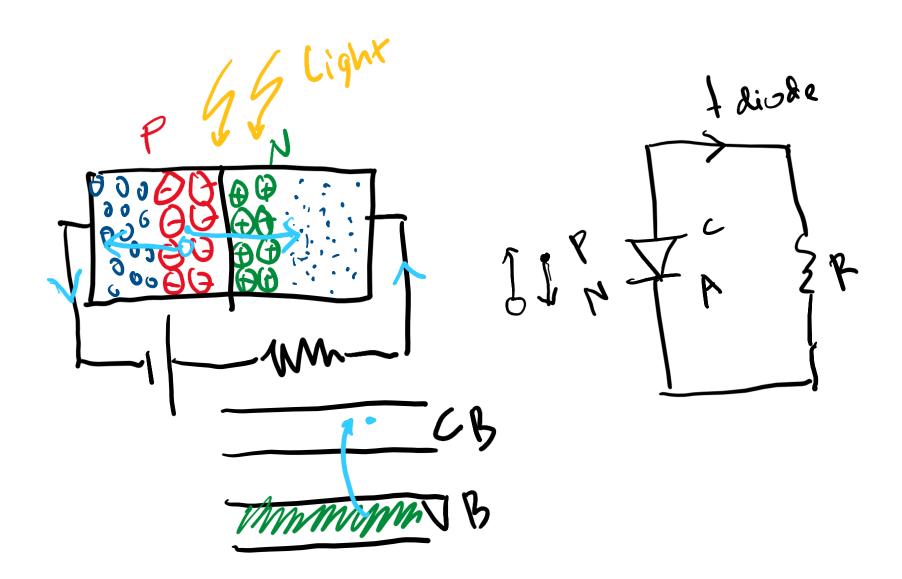
### How does a photodiode work





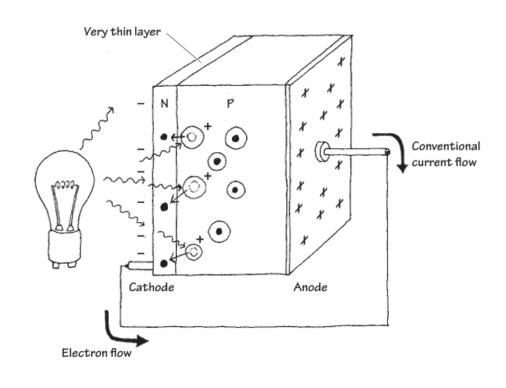
### How does a photodiode work





### Photodiode

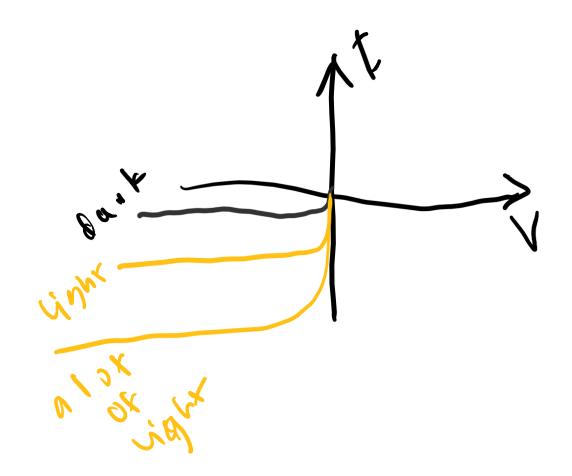






## IV of photodiode





### The PD in our demo board

https://www.vishay.co m/docs/83493/vemd2 023slx01.pdf



#### VEMD2023SLX01

### Vishay Semiconductors

RoHS

HALOGEN

FREE

GREEN

#### Silicon PIN Photodiode



#### DESCRIPTION

VEMD2023SLX01 is a high speed and high sensitive PIN photodiode in a miniature side looking, surface mount package (SMD) with dome lens and daylight blocking filter. Filter is matched with IR emitters operating at wavelength of 830 nm to 950 nm. The photo sensitive area of the chip is 0.23 mm<sup>2</sup>.

#### **FEATURES**

- · Package type: surface mount
- · Package form: side view
- Dimensions (L x W x H in mm): 2.3 x 2.55 x 2.3
- · AEC-Q101 qualified
- · High radiant sensitivity
- · Daylight blocking filter matched with 830 nm to 950 nm IR emitters
- · Fast response times
- Angle of half sensitivity: φ = ± 35°
- · Package matched with IR emitter series VSMB2943SLX01
- . Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- · Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

#### **APPLICATIONS**

- · High speed photo detector
- · Infrared remote control
- · Infrared data transmission
- · Photo interrupters
- · IR touch panels

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μA)	φ (deg)	λ <sub>0.5</sub> (nm)
VEMD2023SLX01	10	± 35	750 to 1060

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATI	DERING INFORMATION		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VEMD2023SLX01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	Side view

· MOQ: minimum order quantity

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	60	٧
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	215	mW
Junction temperature		T <sub>j</sub>	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	ŝ
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	Acc. reflow solder profile fig. 7	T <sub>sd</sub>	260	°c
Thermal resistance junction/ambient	Acc. J-STD-061	R <sub>th.IA</sub>	250	K/W



### PD characteristics



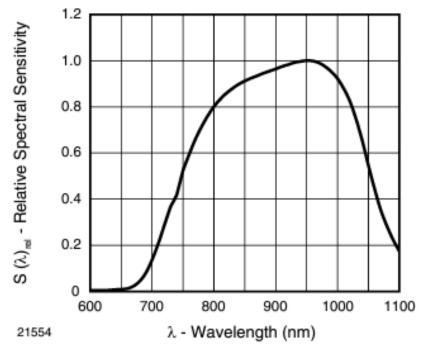


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

#### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

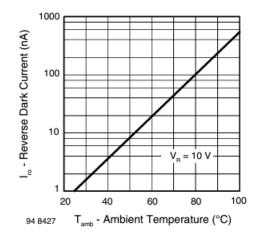


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

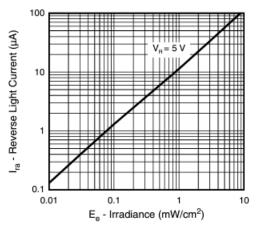


Fig. 3 - Reverse Light Current vs. Irradiance

### LED-PD combo



